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Sommario/riassunto	<p>Annotation CSW 2016 will be the premier forum of 2016 for science, technology and applications of compound semiconductors, addressing the physics, science, and applications of III V and II VI compound semiconductors, SiGe, SiC and related alloys, as well as new materials such as complex oxides and two dimensional materials. Papers are solicited on all compound semiconductor related topics including (IPRM) Epitaxy, novel materials, and nanostructures, Optoelectronics devices and related technologies, Electron devices and related technologies, (ISCS) Growth and related technologies, Photonic devices, Nanocharacterization and nanostructures, Oxide semiconductors, Organic semiconductors and flexible materials, High frequency and high power devices, Physics, spintronics, and novel device concepts, GaN and related semiconductors, Nanocarbon and novel 2D materials.</p>